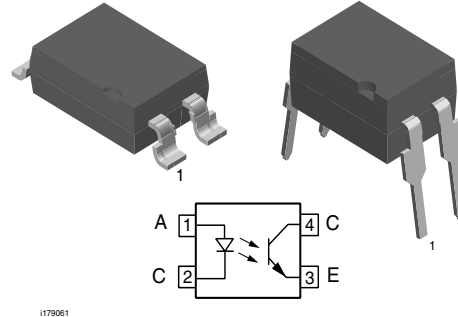


## Optocoupler, Phototransistor Output, Low Input Current

### Features

- Good CTR Linearity Depending on Forward Current
- Low CTR Degradation
- High Collector-emitter Voltage,  $V_{CE0} = 55\text{ V}$
- Isolation Test Voltage,  $5300\text{ V}_{RMS}$
- Low Coupling Capacitance
- End-Stackable, 0.100 " (2.54 mm) Spacing
- High Common-mode Interference Immunity
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- CSA 93751
- DIN EN 60747-5-2 (VDE0884)  
DIN EN 60747-5-5 pending  
Available with Option 1

### Applications

Telecom  
Industrial Controls  
Battery Powered Equipment  
Office Machines

### Description

The SFH618A (DIP) and SFH6186 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm lead spacing.

Creepage and clearance distances of > 8.0 mm achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation to an operation voltage of  $400\text{ V}_{RMS}$  or DC.

### Order Information

Part	Remarks
SFH618A-2	CTR 63 - 125 %, DIP-4
SFH618A-3	CTR 100 - 200 %, DIP-4
SFH618A-4	CTR 160 - 320 %, DIP-4
SFH618A-5	CTR 250 - 500 %, DIP-4
SFH6186-2	CTR 63 - 125 %, SMD-4
SFH6186-3	CTR 100 - 200 %, SMD-4
SFH6186-4	CTR 160 - 320 %, SMD-4
SFH6186-5	CTR 250 - 500 %, SMD-4
SFH618A-3X006	CTR 100 - 200 %, DIP-4 400 mil (option 6)
SFH618A-3X007	CTR 100 - 200 %, SMD-4 (option 7)
SFH618A-4X006	CTR 160 - 320 %, DIP-4 400 mil (option 6)
SFH618A-5X006	CTR 250 - 500 %, DIP-4 400 mil (option 6)
SFH618A-5X007	CTR 250 - 500 %, SMD-4 (option 7)

For additional information on the available options refer to Option Information.

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

### Input

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6.0	V
Power dissipation		$P_{diss}$		mW
Forward current		$I_F$	60	mA

### Output

Parameter	Test condition	Symbol	Value	Unit
Collector-emitter voltage		$V_{CE}$	55	V
Emitter-collector voltage		$V_{EC}$	7.0	V
Collector current		$I_C$	50	mA
	$t_p \leq 1.0\text{ ms}$	$I_C$	100	mA
Power dissipation		$P_{diss}$	150	mW

### Coupler

Parameter	Test condition	Symbol	Value	Unit
Isolation test voltage between emitter and detector, refer to Climate DIN 40046, part2, Nov.74		$V_{ISO}$	5300	$V_{RMS}$
Creepage distance			$\geq 7.0$	mm
Clearance			$\geq 7.0$	mm
Insulation thickness between emitter and detector			$\geq 0.4$	mm
Comparative tracking index per DIN IEC 112/VDEO 303, part 1			175	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{11}$	$\Omega$
Storage temperature range		$T_{stg}$	- 55 to +150	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to +100	$^{\circ}\text{C}$
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Soldering temperature	max. 10 s. Dip Soldering distance to seating plane $\geq 1.5\text{ mm}$	$T_{sld}$	260	$^{\circ}\text{C}$

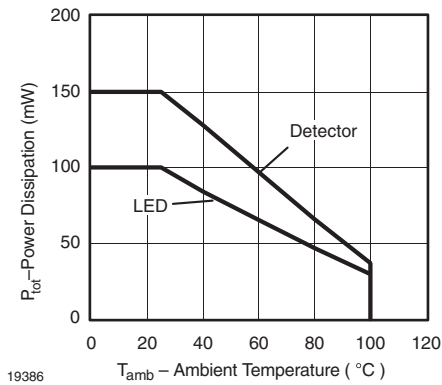


Figure 1. Permissible Power Dissipation vs. Ambient Temperature

## Electrical Characteristics

T<sub>amb</sub> = 25 °C, unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

### Input

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	I <sub>F</sub> = 5.0 mA	V <sub>F</sub>		1.1	1.5	V
Reverse current	V <sub>R</sub> = 6.0 V	I <sub>R</sub>		.01	10	μA
Capacitance	V <sub>R</sub> = 0 V, f = 1.0 MHz	C <sub>O</sub>		25		pF
Thermal resistance		R <sub>thja</sub>		1070		K/W

### Output

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector-emitter leakage current	V <sub>CE</sub> = 10 V	I <sub>CEO</sub>		10	200	nA
Collector-emitter capacitance	V <sub>CE</sub> = 5.0 V, f = 1.0 MHz	C <sub>CE</sub>		7		pF
Thermal resistance		R <sub>thja</sub>		500		K/W

### Coupler

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Collector-emitter saturation voltage	I <sub>C</sub> = 0.32 mA, I <sub>F</sub> = 1.0 mA	SFH618A-2 SFH6186-2	V <sub>CEsat</sub>		0.25	0.4	V
	I <sub>C</sub> = 0.5 mA, I <sub>F</sub> = 1.0 mA	SFH618A-3 SFH6186-3	V <sub>CEsat</sub>		0.25	0.4	V
	I <sub>C</sub> = 1.25 mA, I <sub>F</sub> = 1.0 mA	SFH618A-4 SFH6186-4	V <sub>CEsat</sub>		0.25	0.4	V
	I <sub>C</sub> = 0.8 mA, I <sub>F</sub> = 1.0 mA	SFH618A-5 SFH6186-5	V <sub>CEsat</sub>		0.25	0.4	V
Coupling capacitance			C <sub>C</sub>		0.25		pF

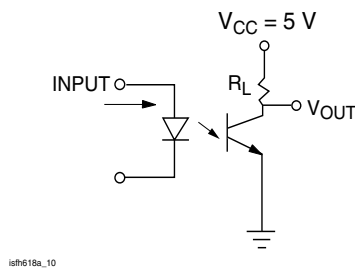
## Current Transfer Ratio

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
$I_C/I_F$	$I_F = 1.0 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH618A-2 SFH6186-2	CTR	63		125	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH618A-2 SFH6186-2	CTR	32	75		%
	$I_F = 1.0 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH618A-3 SFH6186-3	CTR	100		200	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH618A-3 SFH6186-3	CTR	50	120		%
	$I_F = 1.0 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH618A-4 SFH6186-4	CTR	160		320	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH618A-4 SFH6186-4	CTR	80	200		%
	$I_F = 1.0 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH618A-5 SFH6186-5	CTR	250		500	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH618A-5 SFH6186-5	CTR	125	300		%

## Switching Characteristics

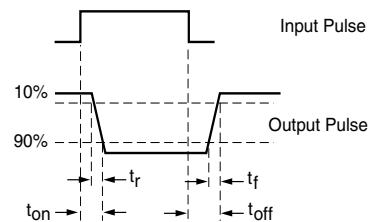
Typical

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Turn-on time	$V_{CC} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}, R_L = 100 \Omega$	$t_{on}$		6.0		$\mu\text{s}$
Rise time	$V_{CC} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}, R_L = 100 \Omega$	$t_r$		3.5		$\mu\text{s}$
Turn-off time	$V_{CC} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}, R_L = 100 \Omega$	$t_{off}$		5.5		$\mu\text{s}$
Fall time	$V_{CC} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}, R_L = 100 \Omega$	$t_f$		5.0		$\mu\text{s}$



sfh618a\_10

Figure 2. Test Circuit



sfh618a\_12

Figure 3. Test Circuit and Waveforms

## Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

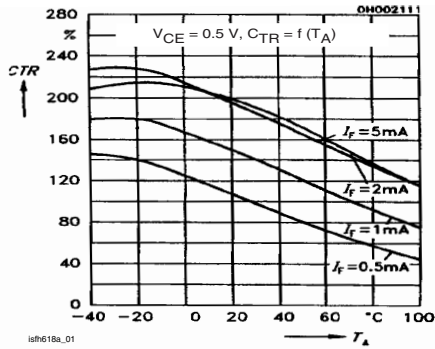


Figure 4. Current Transfer Ratio (typ.)

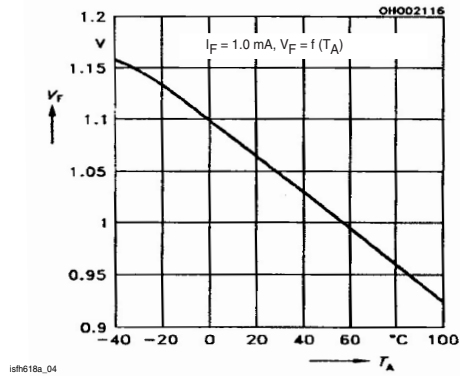


Figure 7. Diode Forward Voltage (typ.)

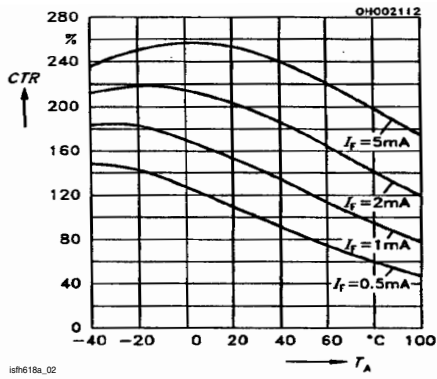


Figure 5. Current Transfer Ratio (typ.)

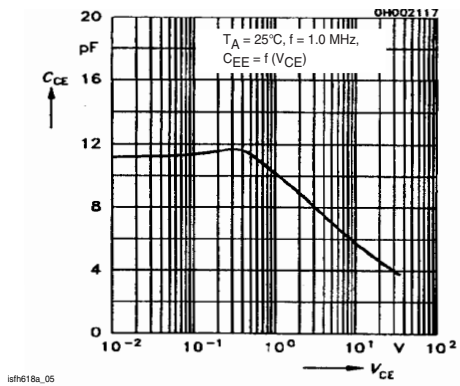


Figure 8. Transistor Capacitance

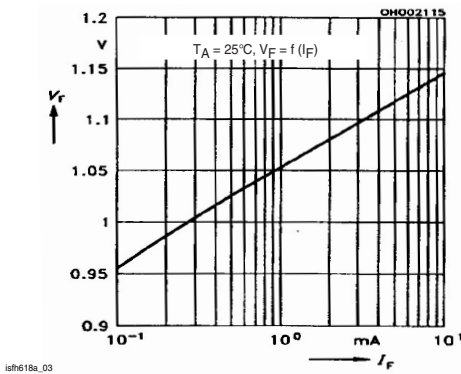


Figure 6. Diode Forward Voltage (typ.)

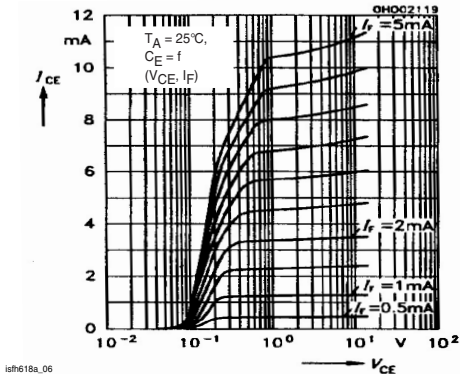


Figure 9. Output Characteristics

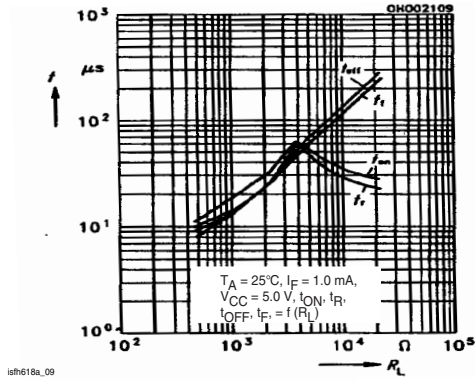
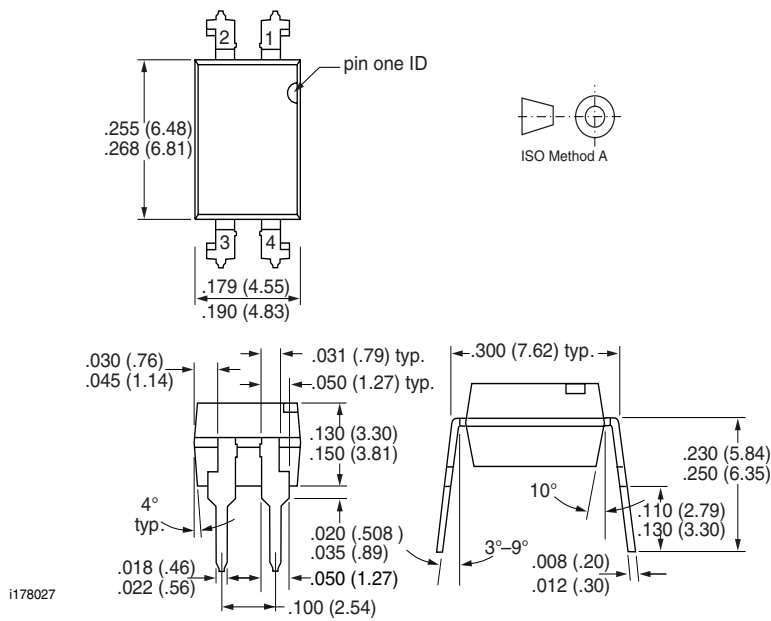
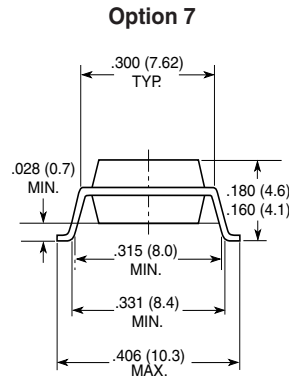
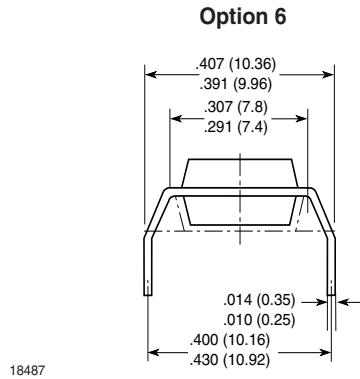
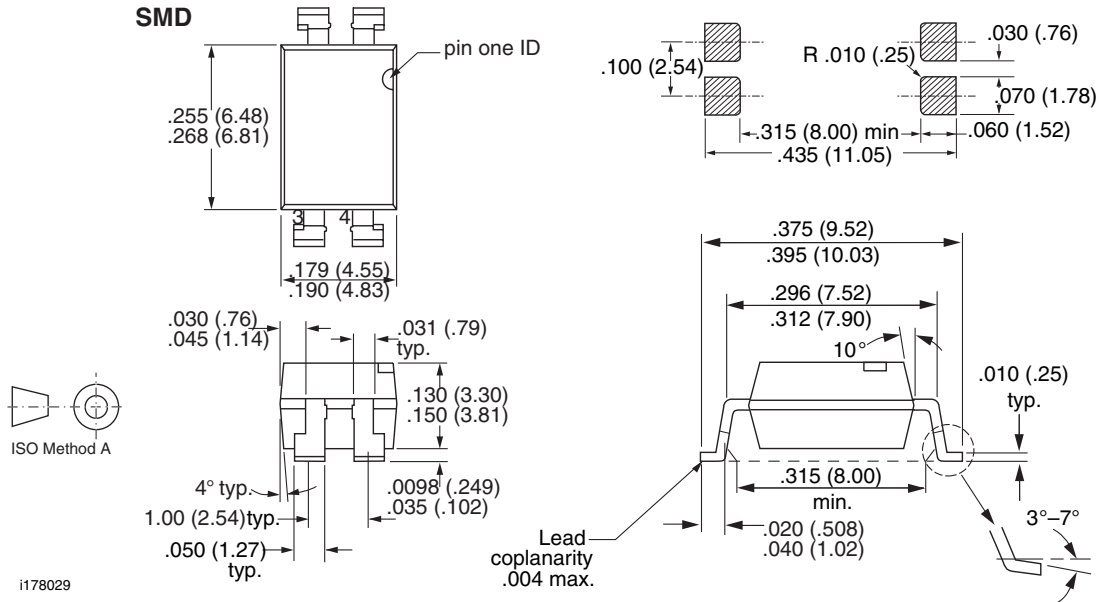


Figure 10. Switching times (typ.)

## Package Dimensions in Inches (mm)



## Package Dimensions in Inches (mm)



### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
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